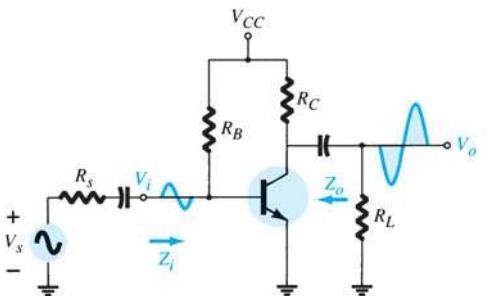
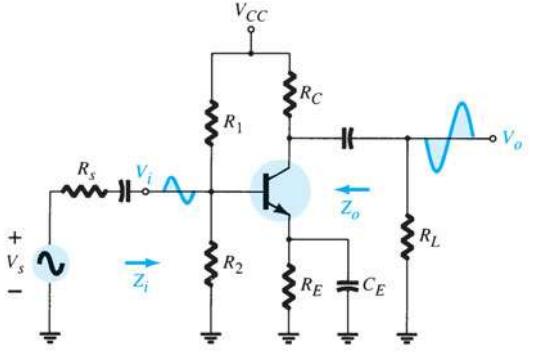
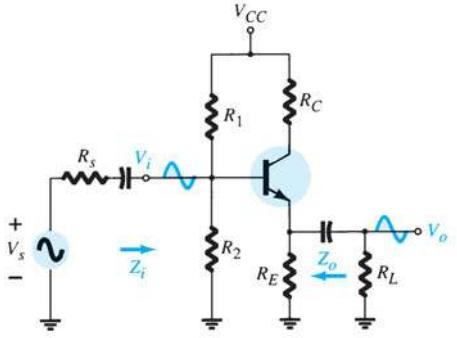
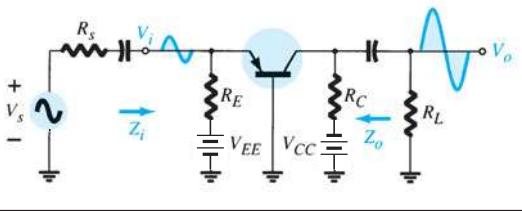
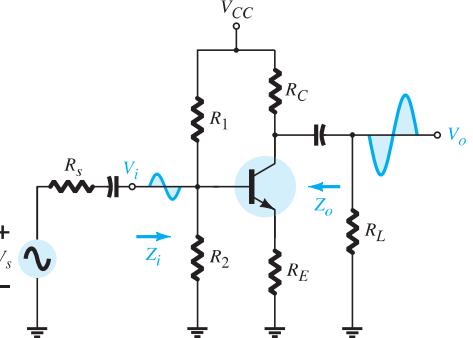


TABLE 5.1
Unloaded BJT Transistor Amplifiers

Configuration	Z_i	Z_o	A_v	A_i
Fixed-bias:				
	Medium ($1\text{ k}\Omega$) $= R_B \parallel \beta r_e$ $\cong \beta r_e$ $(R_B \geq 10\beta r_e)$	Medium ($2\text{ k}\Omega$) $= R_C \parallel r_o$ $\cong R_C$ $(r_o \geq 10R_C)$	High (-200) $= -\frac{(R_C \parallel r_o)}{r_e}$ $\cong -\frac{R_C}{r_e}$ $(r_o \geq 10R_C, R_B \geq 10\beta r_e)$	High (100) $= \frac{\beta R_B r_o}{(r_o + R_C)(R_B + \beta r_e)}$ $\cong \beta$ $(r_o \geq 10R_C, R_B \geq 10\beta r_e)$
Voltage-divider bias:				
	Medium ($1\text{ k}\Omega$) $= R_1 \parallel R_2 \parallel \beta r_e$	Medium ($2\text{ k}\Omega$) $= R_C \parallel r_o$ $\cong R_C$ $(r_o \geq 10R_C)$	High (-200) $= -\frac{R_C \parallel r_o}{r_e}$ $\cong -\frac{R_C}{r_e}$ $(r_o \geq 10R_C)$	High (50) $= \frac{\beta(R_1 \parallel R_2)r_o}{(r_o + R_C)(R_1 \parallel R_2 + \beta r_e)}$ $\cong \frac{\beta(R_1 \parallel R_2)}{R_1 \parallel R_2 + \beta r_e}$ $(r_o \geq 10R_C)$
Unbypassed emitter bias:				
	High ($100\text{ k}\Omega$) $= R_B \parallel Z_b$ $Z_b \cong \beta(r_e + R_E)$ $\cong R_B \parallel \beta R_E$ $(R_E \gg r_e)$	Medium ($2\text{ k}\Omega$) $= R_C$ $(\text{any level of } r_o)$	Low (-5) $= -\frac{R_C}{r_e + R_E}$ $\cong -\frac{R_C}{R_E}$ $(R_E \gg r_e)$	High (50) $\cong -\frac{\beta R_B}{R_B + Z_b}$
Emitter-follower:				
	High ($100\text{ k}\Omega$) $= R_B \parallel Z_b$ $Z_b \cong \beta(r_e + R_E)$ $\cong R_B \parallel \beta R_E$ $(R_E \gg r_e)$	Low ($20\ \Omega$) $= R_E \parallel r_e$ $\cong r_e$ $(R_E \gg r_e)$	Low ($\cong 1$) $= \frac{R_E}{R_E + r_e}$ $\cong 1$	High (-50) $\cong -\frac{\beta R_B}{R_B + Z_b}$
Common-base:				
	Low ($20\ \Omega$) $= R_E \parallel r_e$ $\cong r_e$ $(R_E \gg r_e)$	Medium ($2\text{ k}\Omega$) $= R_C$	High (200) $\cong \frac{R_C}{r_e}$	Low (-1) $\cong -1$
Collector feedback:				
	Medium ($1\text{ k}\Omega$) $= \frac{r_e}{\frac{1}{\beta} + \frac{R_C}{R_F}}$ $\cong R_C \parallel R_F$ $(r_o \geq 10R_C)$	Medium ($2\text{ k}\Omega$) $\cong R_C \parallel R_F$	High (-200) $\cong -\frac{R_C}{r_e}$ $(r_o \geq 10R_C, R_F \gg R_C)$	High (50) $= \frac{\beta R_F}{R_F + \beta R_C}$ $\cong \frac{R_F}{R_C}$

TABLE 5.2
BJT Transistor Amplifiers Including the Effect of R_s and R_L

Configuration	$A_{vL} = V_o/V_i$	Z_i	Z_o
	$\frac{-(R_L \ R_C)}{r_e}$	$R_B \ \beta r_e$	R_C
	Including r_o :	$\frac{-(R_L \ R_C \ r_o)}{r_e}$	$R_B \ \beta r_e$
	$\frac{-(R_L \ R_C)}{r_e}$	$R_1 \ R_2 \ \beta r_e$	R_C
	Including r_o :	$\frac{-(R_L \ R_C \ r_o)}{r_e}$	$R_1 \ R_2 \ \beta r_e$
	≈ 1	$R'_E = R_L \ R_E$	$R'_s = R_s \ R_1 \ R_2$
	Including r_o :	$R_1 \ R_2 \ \beta(r_e + R'_E)$	$R_E \ \left(\frac{R'_s}{\beta} + r_e \right)$
	$\approx \frac{-(R_L \ R_C)}{r_e}$	$R_E \ r_e$	R_C
	Including r_o :	$\approx \frac{-(R_L \ R_C \ r_o)}{r_e}$	$R_E \ r_e$
	$\frac{-(R_L \ R_C)}{R_E}$	$R_1 \ R_2 \ \beta(r_e + R_E)$	R_C
	Including r_o :	$\frac{-(R_L \ R_C \ r_o)}{R_E}$	$R_1 \ R_2 \ \beta(r_e + R_E)$